# onsemi

# Field Effect Transistor -N-Channel, Enhancement Mode

# 2N7002K

# Features

- Low On–Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input / Output Leakage
- Ultra-Small Surface Mount Package
- ESD HBM = 2000 V (Typical: 3000 V) as per JESD22 A114 and ESD CDM = 2000 V as per JESD22 C101
- This Device is Pb–Free, Halogen Free/BFR Free and is RoHS Compliant

Symbol	Para	Value	Unit	
V <sub>DSS</sub>	Drain-Source Voltag	Drain-Source Voltage		
V <sub>DGR</sub>	Drain–Gate Voltage ( $R_{GS} \le 1.0 \text{ M}\Omega$ )		60	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current Continuous		300	mA
	Pulsed		800	
TJ	Operating Junction T	-55 to +150	°C	
T <sub>STG</sub>	Storage Temperature	e Range	–55 to +150	°C

# **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub> = 25°C unless otherwise specified)

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

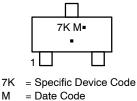
Symbol	Parameter	Value	Unit
PD	Total Device Dissipation	350	mW
	Derate Above T <sub>A</sub> = 25°C	2.8	mW/°C
$R_{\thetaJA}$	Thermal Resistance, Junction-to-Ambient (Note 1)	350	°C/W

1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; Minimum land pad size.

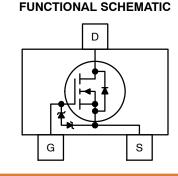


SOT-23 (TO-236) CASE 318-08

# MARKING DIAGRAM



- = Pb-Free Package
- (Note: Microdot may be in either location)
- \*Date Code orientation may vary depending upon manufacturing location.



## **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

# 2N7002K

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Max	Unit
OFF CHARA	ACTERISTICS (Note 2)				
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	$V_{GS}$ = 0 V, $I_D$ = 10 $\mu$ A	60	-	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	-	1.0	μA
		$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125^{\circ}\text{C}$	-	500	
I <sub>GSS</sub>	Gate-Body Leakage	$V_{GS}$ = ±20 V, $V_{DS}$ = 0 V	-	±10	μΑ

#### **ON CHARACTERISTICS** (Note 2)

V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	1.0	2.5	V
R <sub>DS(ON)</sub>	Static Drain-Source On-Resistance	$V_{GS}$ = 10 V, I <sub>D</sub> = 0.5 A	-	2	Ω
		$V_{GS}$ = 4.5 V, I <sub>D</sub> = 200 mA	-	4	
I <sub>D(ON)</sub>	On-State Drain Current	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 7.5 V	1.5	-	А
<b>9</b> FS	Forward Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.2 A	200	-	mS

#### DYNAMIC CHARACTERISTICS

C <sub>iss</sub>	Input Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}, f = 1.0 \text{ MHz}$	-	50	pF
C <sub>oss</sub>	Output Capacitance		-	15	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	6	pF

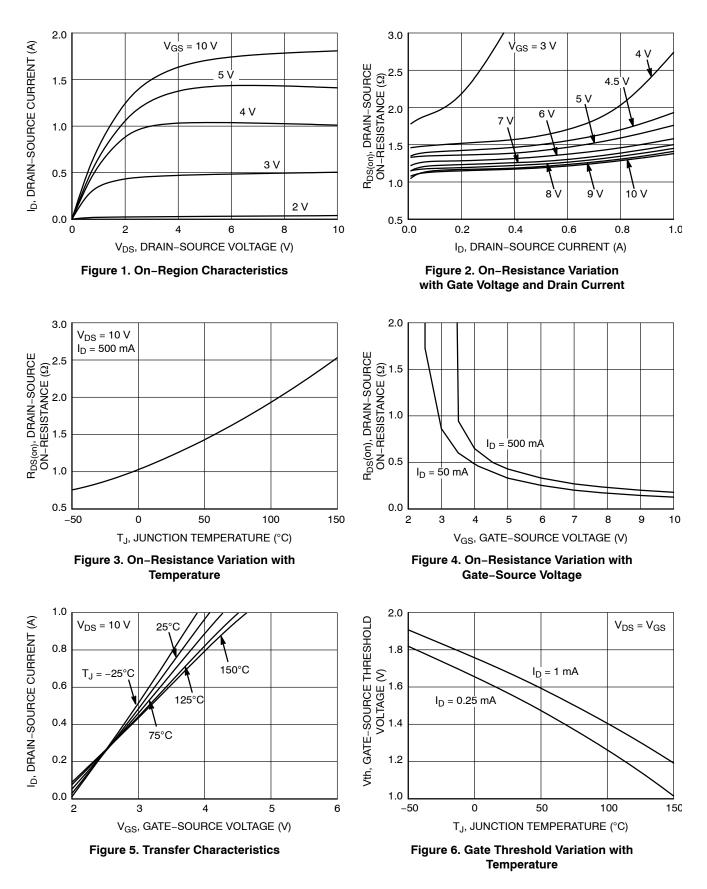
## SWITCHING CHARACTERISTICS

t <sub>D(ON)</sub>	Turn-On Delay Time	$V_{DD}$ = 30 V, $I_{DSS}$ = 200 mA, $R_{G}$ = 10 $\Omega$ , $V_{GS}$ = 10 V	-	5	ns
t <sub>D(OFF)</sub>	Turn-Off Delay Time	V <sub>GS</sub> = 10 V	_	30	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Short duration test pulse used to minimize self-heating effect.

# 2N7002K

# **TYPICAL PERFORMANCE CHARACTERISTICS**



# 2N7002K

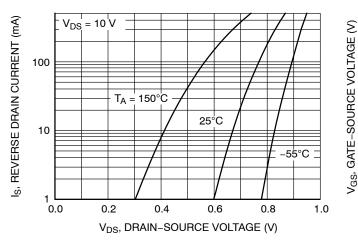


Figure 7. Reverse Drain Current Variation with Diode Forward Voltage and Temperature

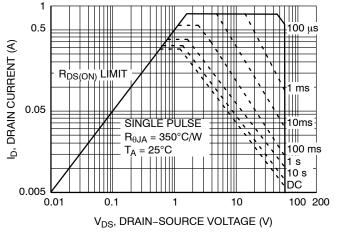


Figure 9. Maximum Safe Operating Area

## **ORDERING INFORMATION**

Part Number	Top Mark	Package	Shipping <sup>†</sup>
2N7002K	7K	SOT-23 3L (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

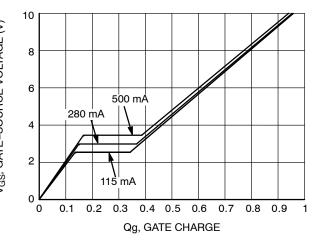


Figure 8. Gate Charge Characteristics

# semi



## SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024













XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS						
DIM	MIN	NOM	МАХ			
А	0.89	1.00	1.11			
A1	0.01	0.06	0.10			
b	0.37	0.44	0.50			
с	0.08	0.14	0.20			
D	2.80	2.90	3.04			
E	1.20	1.30	1.40			
е	1.78	1.90	2.04			
L	0.30	0.43	0.55			
L1	0.35	0.54	0.69			
Ηe	2.10	2.40	2.64			
Т	0°		10°			

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **STYLES ON PAGE 2**

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DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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